

RS2A - RS2M

SURFACE MOUNT FAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 2.0 A

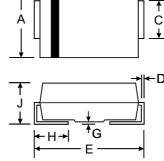
Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Low Power Loss
- Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)





В

| SMB(DO-214AA) | | | | | | | |
|----------------------|------|------|--|--|--|--|--|
| Dim | Min | Max | | | | | |
| Α | 3.30 | 3.94 | | | | | |
| в | 4.06 | 4.70 | | | | | |
| С | 1.91 | 2.21 | | | | | |
| D | 0.15 | 0.31 | | | | | |
| Е | 5.00 | 5.59 | | | | | |
| G | 0.10 | 0.20 | | | | | |
| н | 0.76 | 1.52 | | | | | |
| J | 2.00 | 2.62 | | | | | |
| All Dimensions in mm | | | | | | | |

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | RS2A | RS2B | RS2D | RS2G | RS2J | RS2K | RS2M | Unit |
|---|--|-------------|------|------|------|------|------|------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm Vrwm Vr | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | VR(RMS) | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Rectified Output Current $@T_L = 90^{\circ}C$ | ю | 2.0 | | | | | | | А |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | gle half sine-wave superimposed on IFSM 50 | | | | | A | | | |
| Forward Voltage $@I_F = 2.0A$ | Vfm | 1.30 | | | | | | V | |
| Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$ | IRM | 5.0 300 | | | | | | | μA |
| Reverse Recovery Time (Note 1) | trr | 150 250 500 | | | | | | nS | |
| Typical Junction Capacitance (Note 2) | Cj | 50 | | | | | | | pF |
| Typical Thermal Resistance (Note 3) | R∉JL | 20 | | | | | | | °C/W |
| Operating and Storage Temperature Range | Tj, Ts⊤g | -50 to +150 | | | | | | °C | |

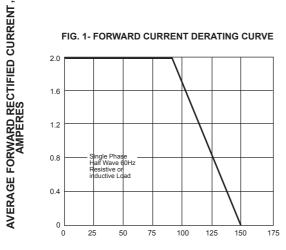
Note: 1. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$. See figure 5.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.

3. Mounted on P.C. Board with 8.0mm² land area.

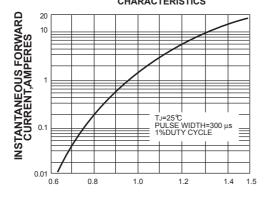


RATINGS AND CHARACTERISTIC CURVES RS2ATHRU RS2M

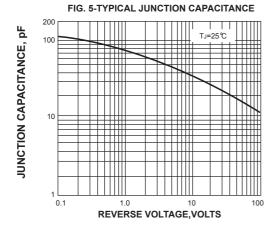


AMBIENT TEMPERATURE, °C





INSTANTANEOUS FORWARD VOLTAGE, VOLTS



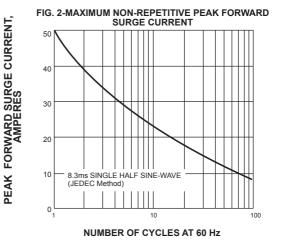
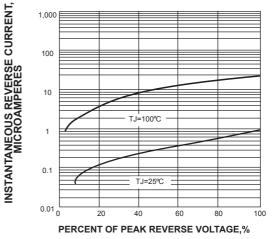
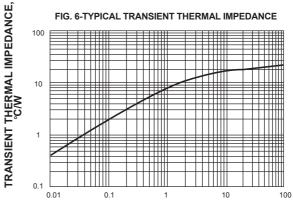


FIG. 4-TYPICAL REVERSE CHARACTERISTICS





t,PULSE DURATION,sec.